

HIGH OUTPUT RS-485 TRANSCEIVERS

DESCRIPTION

The HX65HVD05, HX75HVD05, HX65HVD06, HX75HVD06, HX65HVD07, and HX75HVD07 combine a 3-state differential line driver and differential line receiver. They are designed for balanced data transmission and interoperate with ANSI TIA/EIA-485-A and ISO 8482E standard-compliant devices. The driver is designed to provide a differential output voltage greater than that required by these standards for increased noise margin. The drivers and receivers have active-high and active-low enables respectively, which can be externally connected together to function as direction control.

The driver differential outputs and receiver differential inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus whenever the driver is disabled or not powered. These devices feature wide positive and negative common-mode voltage ranges, making them suitable for party-line applications.

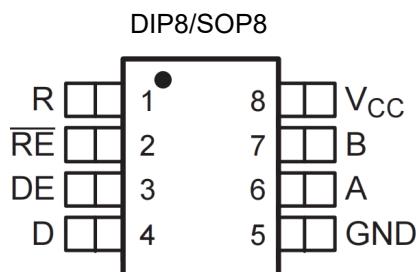
FEATURES

- Minimum Differential Output Voltage of 2.5 V Into a 54- Ω Load
- Open-Circuit, Short-Circuit, and Idle-Bus Failsafe Receiver
- 1/8th Unit-Load Option Available (Up to 256 Nodes on the Bus)
- Bus-Pin ESD Protection Exceeds 16 kV HBM
- Driver Output Slew Rate Control Options
- Electrically Compatible With ANSI TIA/EIA-485-A Standard
- Low-Current Standby Mode...1 μ A Typical
- Glitch-Free Power-Up and Power-Down Protection for Hot-Plugging Applications
- Pin Compatible With Industry Standard SN75176

APPLICATIONS

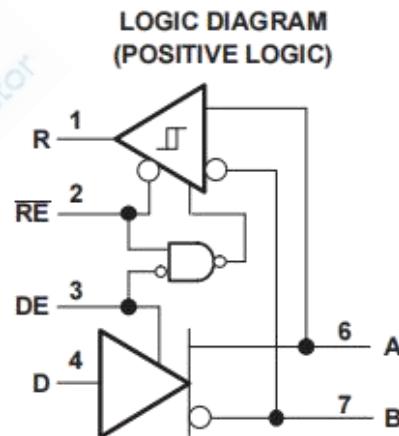
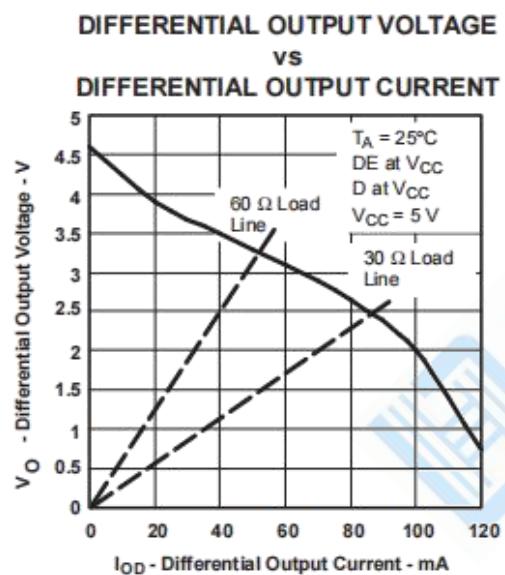
- Data Transmission Over Long or Lossy Lines or Electrically Noisy Environments
- Profibus Line Interface
- Industrial Process Control Networks
- Point-of-Sale (POS) Networks
- Electric Utility Metering
- Building Automation
- Digital Motor Control

Pin Connection



ORDERING INFORMATION

DEVICE	Package Type	MARKING	Packing	Packing Qty
HX65HVD05EIPG	DIP8L	65HVD05	TUBE	2000pcs/box
HX65HVD06EIPG	DIP8L	65HVD06	TUBE	2000pcs/box
HX65HVD07EIPG	DIP8L	65HVD07	TUBE	2000pcs/box
HX75HVD05ECPG	DIP8L	75HVD05	TUBE	2000pcs/box
HX75HVD06ECPG	DIP8L	75HVD06	TUBE	2000pcs/box
HX75HVD07ECPG	DIP8L	75HVD07	TUBE	2000pcs/box
HX65HVD05EIDRG	SOP8L	65HVD05	REEL	2500pcs/reel
HX65HVD06EIDRG	SOP8L	65HVD06	REEL	2500pcs/reel
HX65HVD07EIDRG	SOP8L	65HVD07	REEL	2500pcs/reel
HX75HVD05ECDRG	SOP8L	75HVD05	REEL	2500pcs/reel
HX75HVD06ECDRG	SOP8L	75HVD06	REEL	2500pcs/reel
HX75HVD07ECDRG	SOP8L	75HVD07	REEL	2500pcs/reel



PACKAGE DISSIPATION RATINGS

(See Figure 12 and Figure 13)

PACKAGE	TA ≤ 25°C POWER RATING	DERATING FACTOR(1) ABOVE TA = 25°C	TA = 70°C POWER RATING	TA = 85°C POWER RATING
D(2)	710 mW	5.7 mW/°C	455 mW	369 mW
D(3)	1282 mW	10.3 mW/°C	821 mW	667 mW
P	1000 mW	8.0 mW/°C	640 mW	520 mW

(1) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

(2) Tested in accordance with the Low-K thermal metric definitions of EIA/JESD51-3

(3) Tested in accordance with the High-K thermal metric definitions of EIA/JESD51-7

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted

		HX65HVD05, HX65HVD06, HX65HVD07 HX75HVD05, HX75HVD06, HX75HVD07	
Supply voltage range, V _{CC}		-0.3 V to 6 V	
Voltage range at A or B		-9 V to 14 V	
Input voltage range at D, DE, R or RE		-0.5 V to V _{CC} + 0.5 V	
Voltage input range, transient pulse, A and B, through 100 (see Figure 11)		-50 V to 50 V	
Receiver output current, I _O		-11 mA to 11mA	
Electrostatic discharge	Human body model(3)	A, B, and GND	16 kV
		All pins	4 kV
	Charged-device model(4)	All pins	1 kV
Continuous total power dissipation		See Dissipation Rating Table	

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.
- (3) Tested in accordance with JEDEC Standard 22, Test Method A114-A.
- (4) Tested in accordance with JEDEC Standard 22, Test Method C101.

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.5	5.5		V
Voltage at any bus terminal (separately or common mode) V _I or V _{IC}		-7(1)	12		V
High-level input voltage, V _{IH}	D, DE, \overline{RE}		2		V
Low-level input voltage, V _{IL}	D, DE, \overline{RE}		0.8		V
Differential input voltage, VID (see Figure 7)		-12	12		V
High-level output current, I _{OH}	Driver		-100		mA
	Receiver		-8		
Low-level output current, I _{OL}	Driver		100		mA
	Receiver		8		
Operating free-air temperature, T _A	HX65HVD05				°C
	HX65HVD06				
	HX65HVD07				
	HX75HVD05				°C
	HX75HVD06				
	HX75HVD07				

- (1) The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.

DRIVER ELECTRICAL CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

PARAMETER		TEST CONDITIONS		MIN	TYP(1)	MAX	UNIT
V _{IK}	Input clamp voltage	I _I = -18 mA		-1.5			V
V _{OOL}	Differential output voltage	No Load		V _{CC}			
		R _L = 54Ω, See Figure 4		2.5			V
		V _{test} = -7 V to 12 V, See Figure 2		2.2			
Δ V _{OOL}	Change in magnitude of differential output voltage	See Figure 4 and Figure 2		-0.2		0.2	V
V _{OCS(S)}	Steady-state common-mode output voltage	See Figure 3		2.2		3.3	V
ΔV _{OCS(S)}	Change in steady-state common-mode output voltage			-0.1		0.1	V
V _{OCP(PP)}	Peak-to-peak common-mode output voltage	HVD05 HVD06 HVD07	See Figure 3	600 500 900			mV
I _{OZ}	High-impedance output current	See receiver input currents					
I _I	Input current	D DE		-100 0		0 100	μA
I _{OS}	Short-circuit output current	-7 V V _O 12 V		-250		250	mA
C _(diff)	Differential output capacitance	V _{ID} = 0.4 sin (4E6πt) + 0.5 V, DE at 0 V		16			pF
I _{CC}	Supply current	RE at V _{CC} , D & DE at V _{CC} , No load	Receiver disabled and driver enabled	9	15		mA
		RE at V _{CC} , D at V _{CC} DE at 0 V, No load	Receiver disabled and driver disabled (standby)	1	5		μA
		RE at 0 V, D & DE at V _{CC} , No load	Receiver enabled and driver enabled	9	15		mA

(1) All typical values are at 25°C and with a 5-V supply.

DRIVER SWITCHING CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

PARAMETER		TEST CONDITIONS RL = 54Ω, CL = 50 pF, See Figure 4	MIN	TYP(1)	MAX	UNIT	
tPLH	Propagation delay time, low-to-high-level output		HVD05	6.5	11	ns	
			HVD06	27	40		
			HVD07	250	400		
tPHL	Propagation delay time, high-to-low-level output		HVD05	6.5	11	ns	
			HVD06	27	40		
			HVD07	250	400		
tr	Differential output signal rise time		HVD05	2.7	3.6	ns	
			HVD06	18	28		
			HVD07	150	300	450	
tf	Differential output signal fall time		HVD05	2.7	3.6	ns	
			HVD06	18	28		
			HVD07	150	300	450	
tsk(p)	Pulse skew (tPHL - tPLH)		HVD05	2		ns	
			HVD06	2.5			
			HVD07	10			
tsk(pp) ⁽²⁾	Part-to-part skew		HVD05	3.5		ns	
			HVD06	14			
			HVD07	100			
tPZH1	Propagation delay time, high-impedance-to-high-level output		HVD05	25		ns	
			HVD06	45			
			HVD07	250			
tPHZ	Propagation delay time, high-level-to-high-impedance output		HVD05	25		ns	
			HVD06	60			
			HVD07	250			
tPZL1	Propagation delay time, high-impedance-to-low-level output		HVD05	15		ns	
			HVD06	45			
			HVD07	200			
tPLZ	Propagation delay time, low-level-to-high-impedance output		HVD05	14		ns	
			HVD06	90			
			HVD07	550			
tPZH2	Propagation delay time, standby-to-high-level output	RE = 0 V, RL = 110, See Figure 5	RL = 110Ω, RE at 3 V, See Figure 5	6		μs	
tPZL2	Propagation delay time, standby-to-low-level output	RE = 0 V, RL = 110, See Figure 6	RL = 110Ω, RE at 3 V, See Figure 6	6		μs	

(1) All typical values are at 25°C and with a 5-V supply.

(2) tsk(pp) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

RECEIVER ELECTRICAL CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

PARAMETER	TEST CONDITIONS			MIN	TYP(1)	MAX	UNIT	
V_{IT+} Positive-going input threshold voltage	$I_O = -8 \text{ mA}$			0.01		V		
V_{IT+} Negative-going input threshold voltage	$I_O = 8 \text{ mA}$			-0.2				
V_{hys} Hysteresis voltage ($V_{IT+} - V_{IT-}$)				35		mV		
V_{IK} Enable-input clampvoltage	$I_I = -18 \text{ mA}$			-1.5		V		
V_{OH} High-level output voltage	$V_{ID} = 200 \text{ mV}, I_{OH} = -8 \text{ mA},$ See Figure 7			4		V		
V_{OL} Low-level output voltage	$V_{ID} = -200 \text{ mV}, I_{OL} = 8 \text{ mA},$ See Figure 7			0.4		V		
I_{OZ} High-impedance-state output current	$V_O = 0 \text{ or } V_{CC}$ RE at V_{CC}			-1	1		μA	
I_I Bus input current	HVD05	Other inputat 0 V	$V_A \text{ or } V_B = 12 \text{ V}$	0.23		0.5	mA	
			$V_A \text{ or } V_B = 12 \text{ V}, V_{CC} = 0 \text{ V}$	0.3		0.5		
			$V_A \text{ or } V_B = -7 \text{ V}$	-0.4		0.13		
			$V_A \text{ or } V_B = -7 \text{ V}, V_{CC} = 0 \text{ V}$	-0.4		0.15		
	HVD06 HVD07	Other inputat 0 V	$V_A \text{ or } V_B = 12 \text{ V}$	0.06		0.1	mA	
			$V_A \text{ or } V_B = 12 \text{ V}, V_{CC} = 0 \text{ V}$	0.08		0.13		
			$V_A \text{ or } V_B = -7 \text{ V}$	-0.1		0.05		
			$V_A \text{ or } V_B = -7 \text{ V}, V_{CC} = 0 \text{ V}$	-0.05		0.03		
I_{IH} High-level input current, \overline{RE}	$V_{IH} = 2 \text{ V}$			-60	26.4		μA	
I_{IL} Low-level input current, \overline{RE}	$V_{IL} = 0.8 \text{ V}$			-60	27.4		μA	
$C_{(diff)}$ Differential input capacitance	$V_I = 0.4 \sin (4E6\pi t) + 0.5 \text{ V}, DE \text{ at } 0 \text{ V}$			16		pF		
I_{CC} Supply current	\overline{RE} at 0 V, D & DE at 0 V, No load		Receiver enabled and driver disabled	5		10	mA	
	\overline{RE} at V_{CC} , DE at 0 V,D at V_{CC} , No load		Receiver disabled and driver disabled(standby)	1		5	μA	
	\overline{RE} at 0 V, D & DE at V_{CC} ,No load		Receiver enabled and driver enabled	9		15	mA	

(1) All typical values are at 25°C and with a 5-V supply.

RECEIVER SWITCHING CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
t _{PLH} Propagation delay time, low-to-high-level output 1/2 UL	HVD05 HVD05 HVD06 HVD07 HVD06 HVD07 HVD05 HVD06 HVD07 HVD05	V _{ID} = -1.5 V to 1.5 V, C _L = 15 pF, See Figure 8	14.6	25	ns
t _{PHL} Propagation delay time, high-to-low-level output 1/2 UL			14.6	25	ns
t _{PLH} Propagation delay time, low-to-high-level output 1/8 UL			55	70	ns
t _{PHL} Propagation delay time, high-to-low-level output 1/8 UL			55	70	
t _{PLH} Propagation delay time, low-to-high-level output 1/8 UL			55	70	ns
t _{PHL} Propagation delay time, high-to-low-level output 1/8 UL			55	70	
t _{sk(p)} Pulse skew (t _{PHL} - t _{PLH})			2		ns
t _{sk(p)} Pulse skew (t _{PHL} - t _{PLH})			4.5		
t _{sk(p)} Pulse skew (t _{PHL} - t _{PLH})			4.5		
t _{sk(pp)⁽²⁾} Part-to-part skew	HVD05 HVD06 HVD07	CL = 15 pF, See Figure 8	6.5		ns
t _r Output signal rise time			2	3	
t _f Output signal fall time			2	3	
t _{PZH1} Output enable time to high level		CL = 15 pF, DE at 3 V, See Figure 9	10		ns
t _{PZL1} Output enable time to low level			10		
t _{PHZ} Output disable time from high level			15		
t _{PZL} Output disable time from low level			15		
t _{PZH2} Propagation delay time, standby-to-high-level output		CL = 15 pF, DE at 0, See Figure 10	6		μs
t _{PZL2} Propagation delay time, standby-to-low-level output			6		

(1) All typical values are at 25°C and with a 5-V supply.

(2) t_{sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

PARAMETER MEASUREMENT INFORMATION

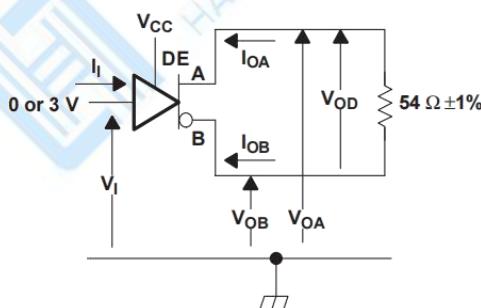


Figure 1. Driver VOD Test Circuit and Voltage and Current Definitions

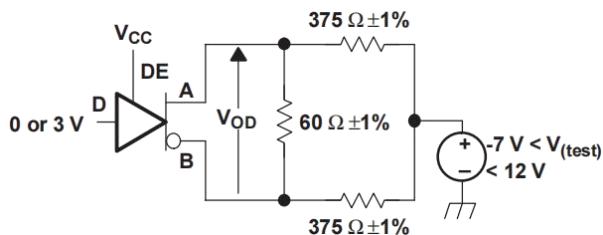
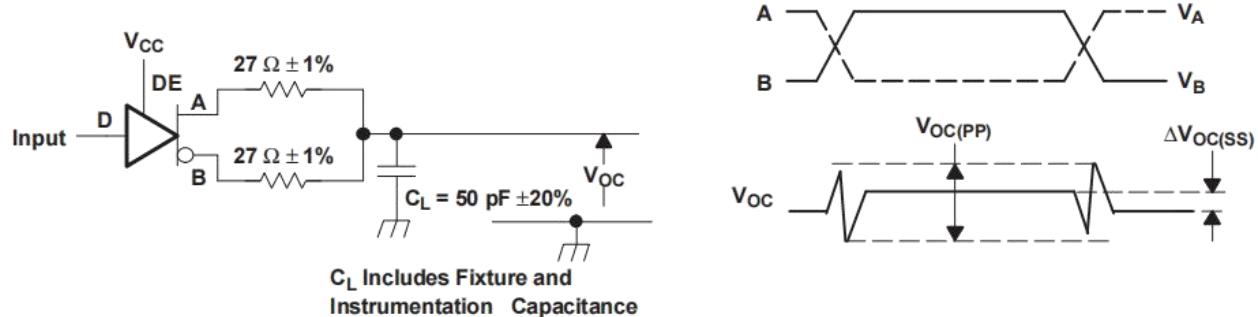
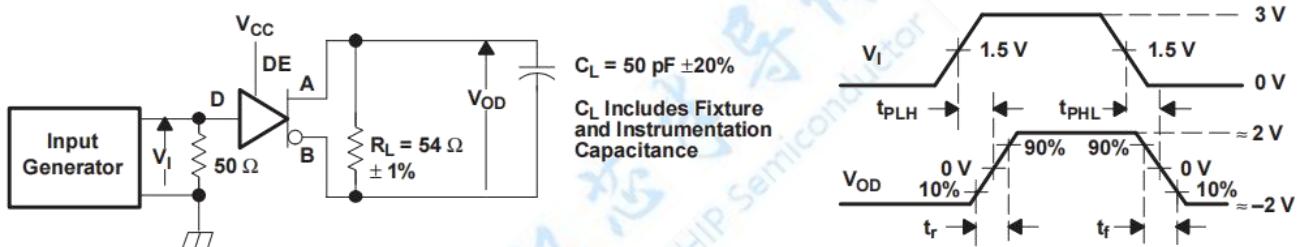


Figure 2. Driver VOD With Common-Mode Loading Test Circuit



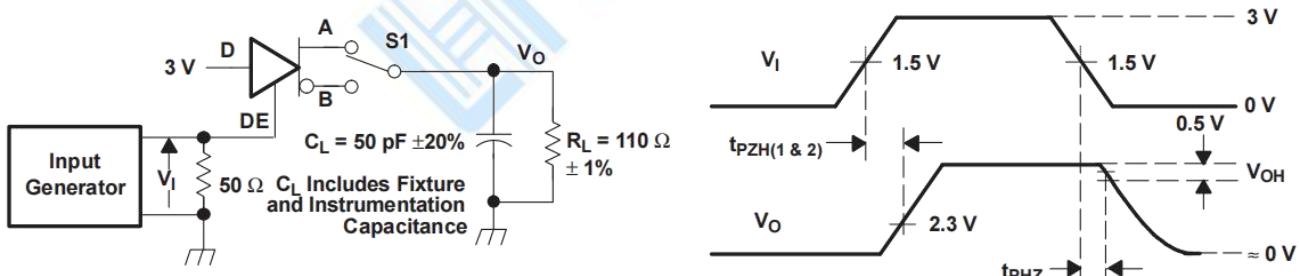
Input: PRR = 500 kHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_0 = 50 \Omega$

Figure 3. Test Circuit and Definitions for the Driver Common-Mode Output Voltage



Generator: PRR = 500 kHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_0 = 50 \Omega$

Figure 4. Driver Switching Test Circuit and Voltage Waveforms



Generator: PRR = 100 kHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_0 = 50 \Omega$

Figure 5. Driver High-Level Enable and Disable Time Test Circuit and Voltage Waveforms

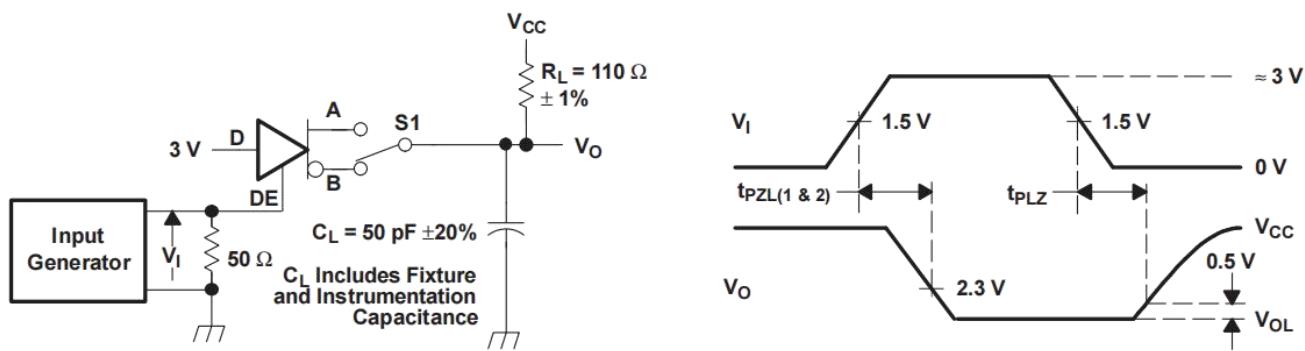


Figure 6. Driver Low-Level Output Enable and Disable Time Test Circuit and Voltage Waveforms

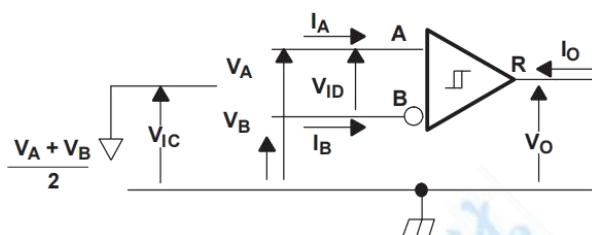


Figure 7. Receiver Voltage and Current Definitions

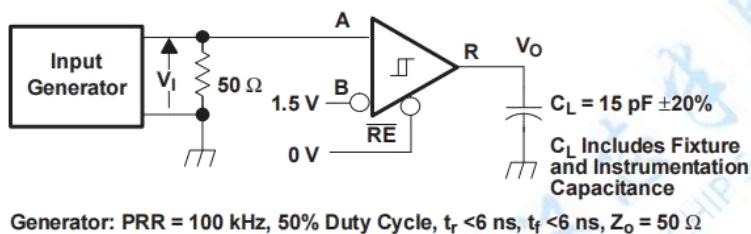


Figure 8. Receiver Switching Test Circuit and Voltage Waveforms

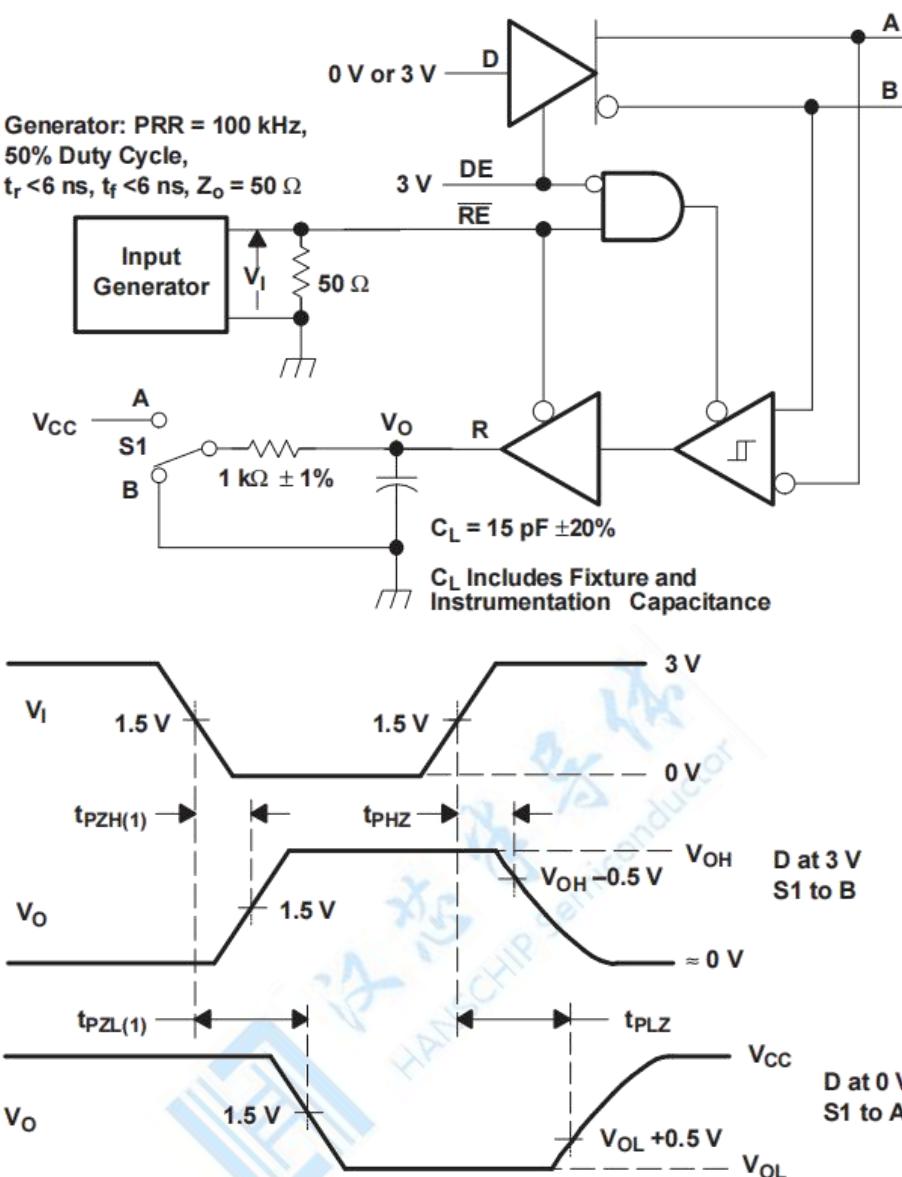


Figure 9. Receiver Enable and Disable Time Test Circuit and Voltage Waveforms With Drivers Enabled

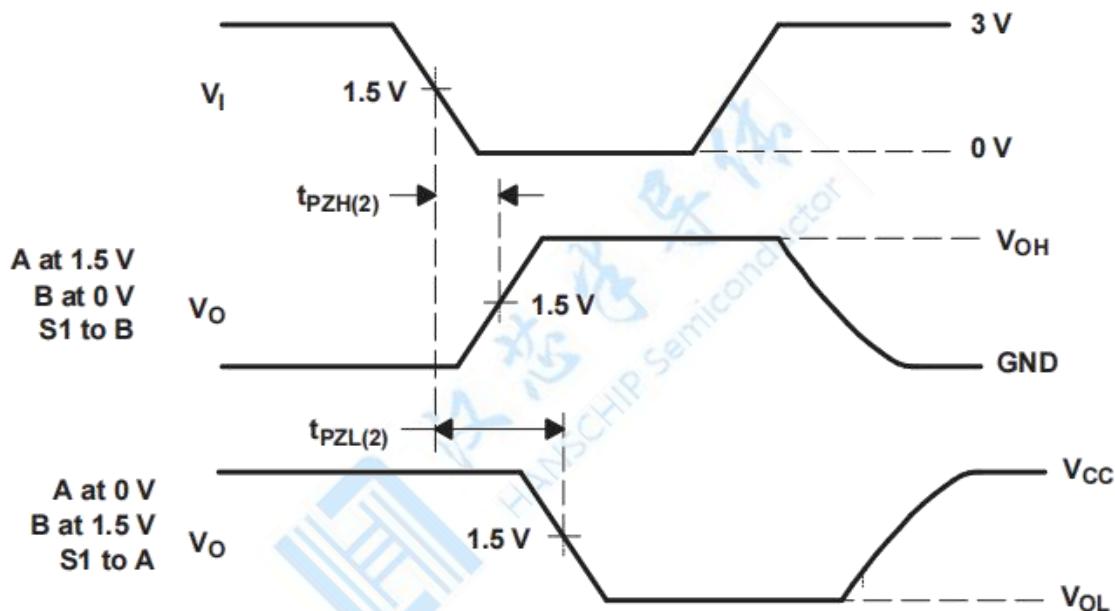
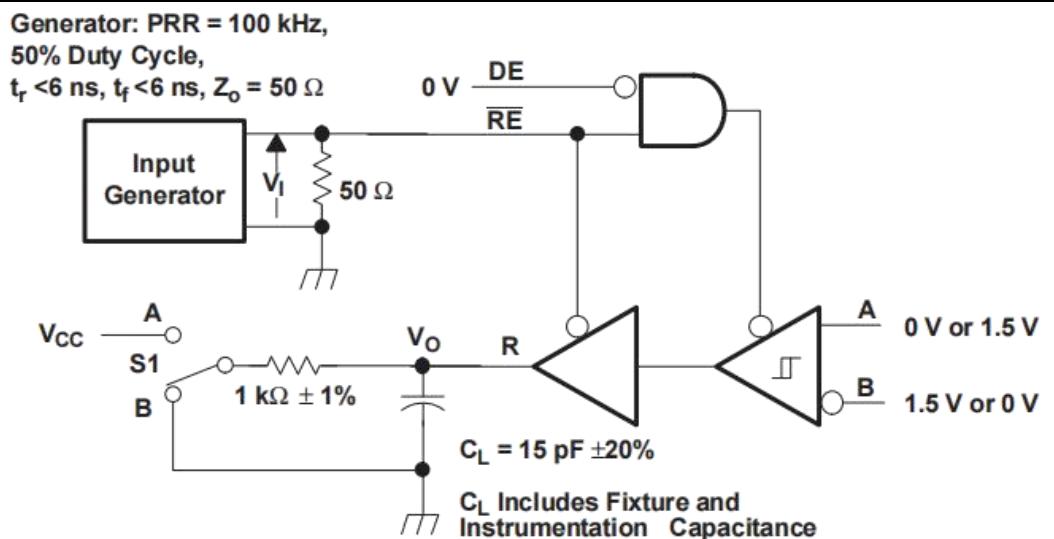
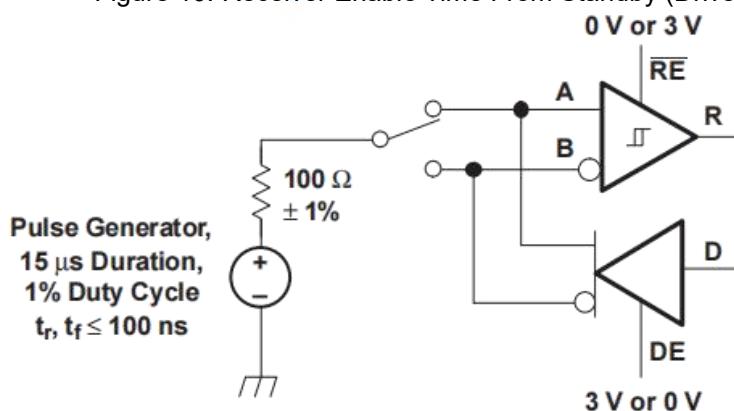


Figure 10. Receiver Enable Time From Standby (Driver Disabled)



NOTE: This test is conducted to test survivability only. Data stability at the R output is not specified.

Figure 11. Test Circuit, Transient Over Voltage Test

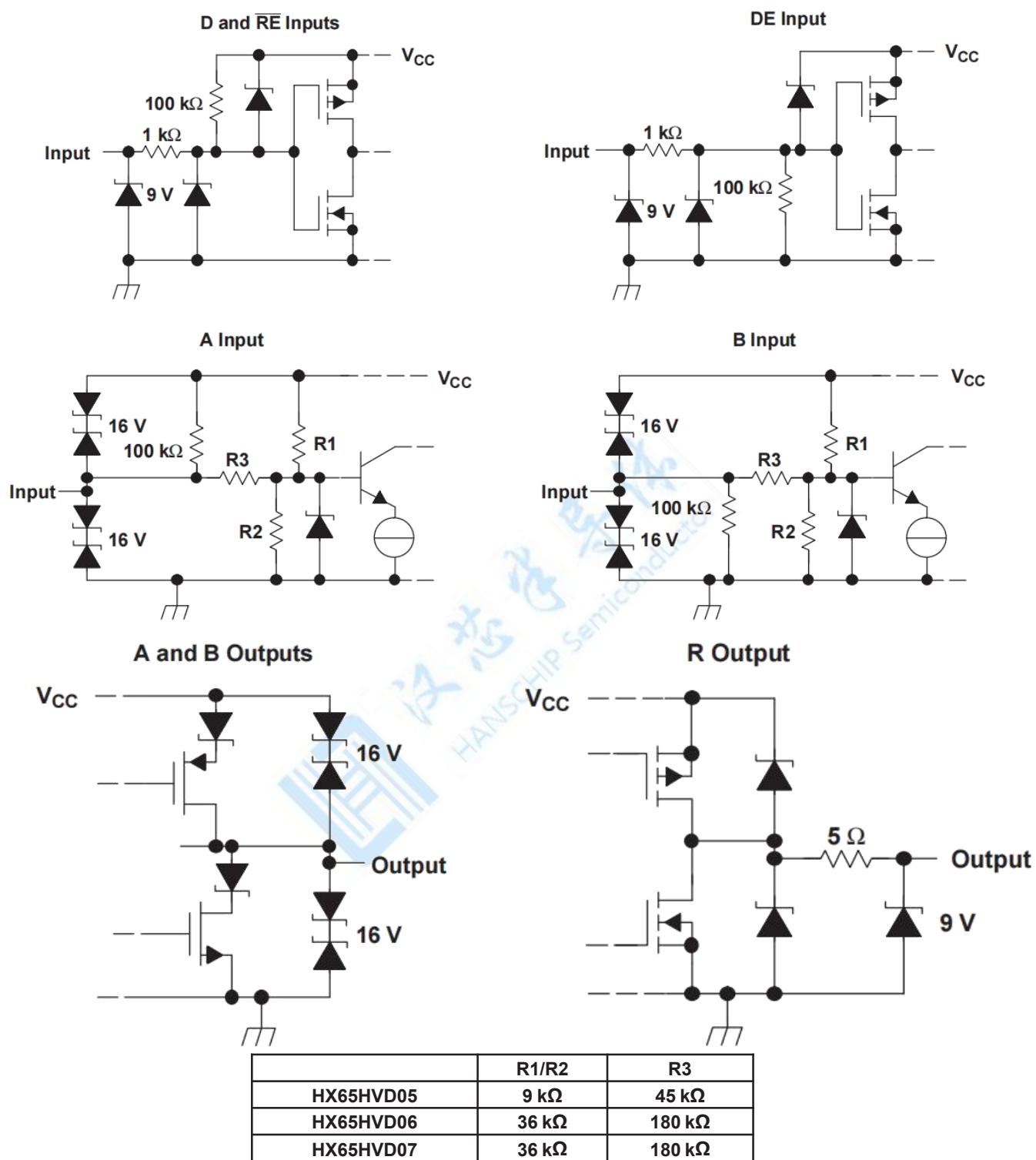
FUNCTION TABLES

INPUT D	ENABLE DE	OUTPUTS	
		A	B
H	H	H	L
L	H	L	H
X	L	Z	Z
Open	H	H	L
X	Open	Z	Z

RECEIVER(1)

DIFFERENTIAL INPUTS $V_{ID} = V_A - V_B$	ENABLE RE	OUTPUT R
$V_{ID} \leq -0.2\text{ V}$	L	L
$-0.2\text{ V} < V_{ID} < -0.01\text{ V}$	L	?
$-0.01\text{ V} \leq V_{ID}$	L	H
X	H	Z
Open Circuit	L	H
Short Circuit	L	H
X	Open	Z

(1) H = high level; L = low level; Z = high impedance; X = irrelevant; ? = indeterminate

EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS


TYPICAL CHARACTERISTICS

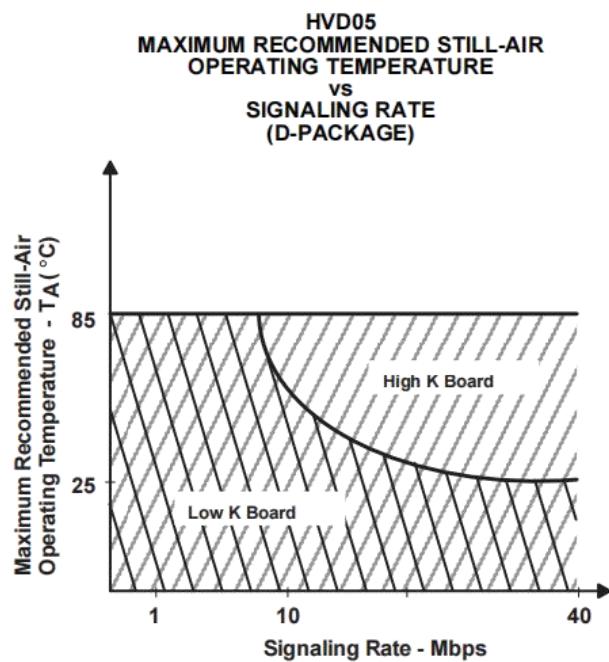


Figure 12.

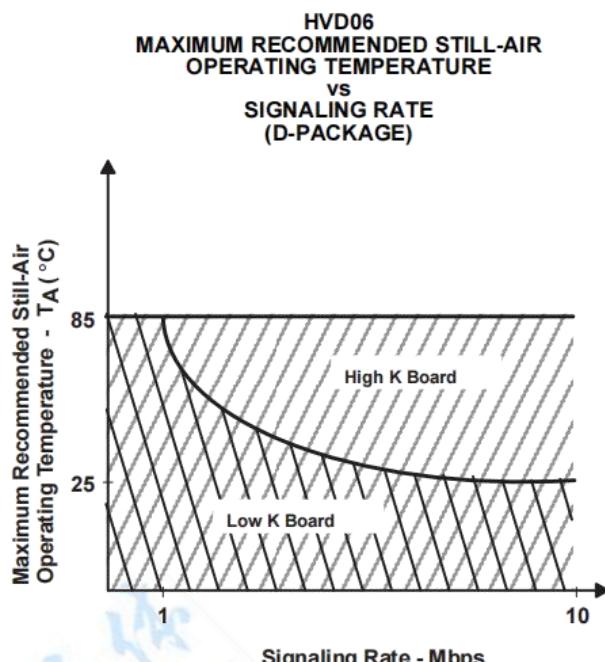


Figure 13.

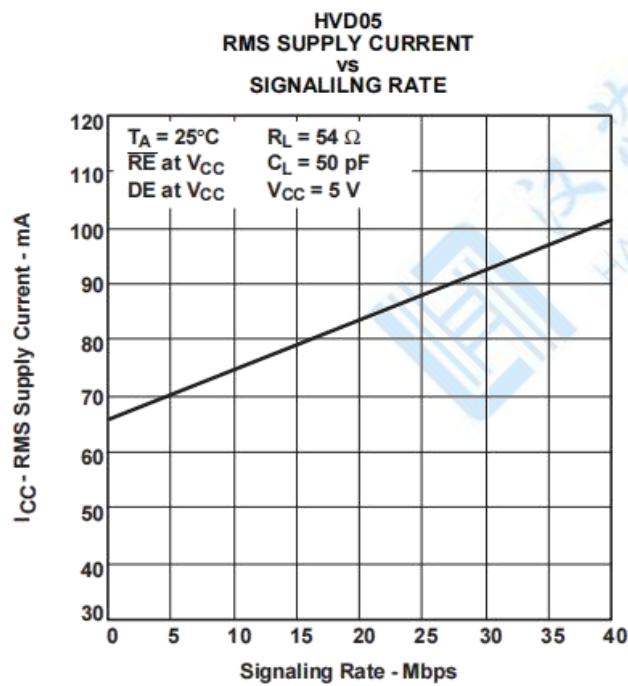


Figure 14.

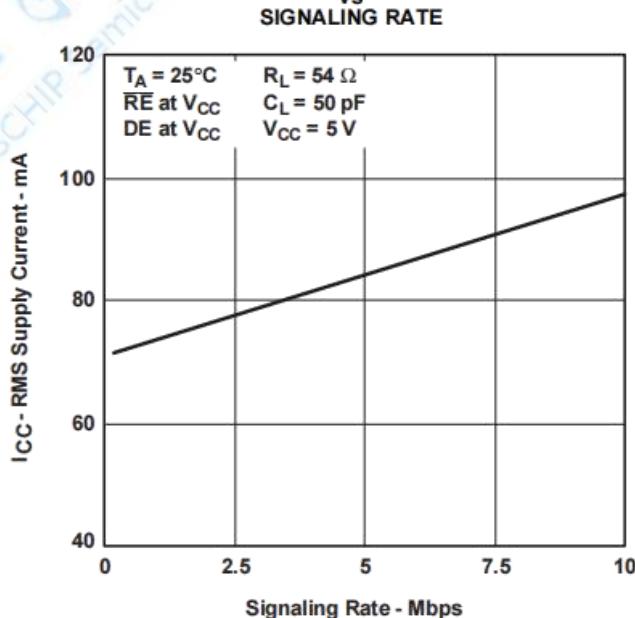


Figure 15.

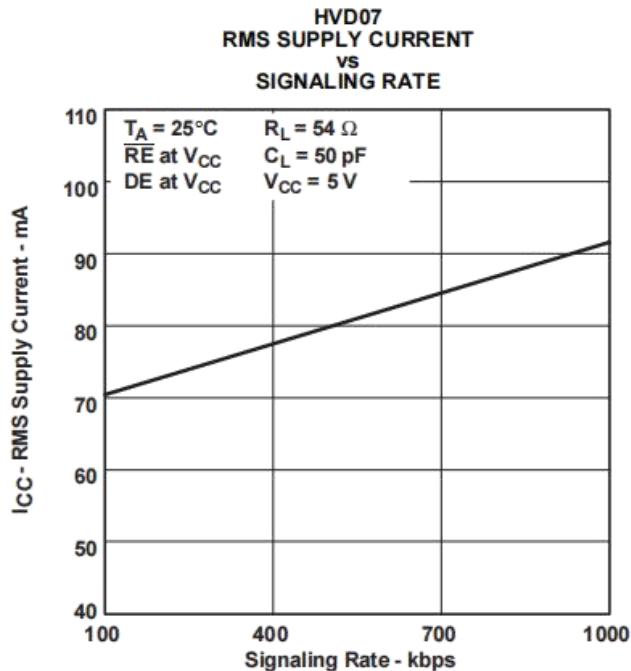


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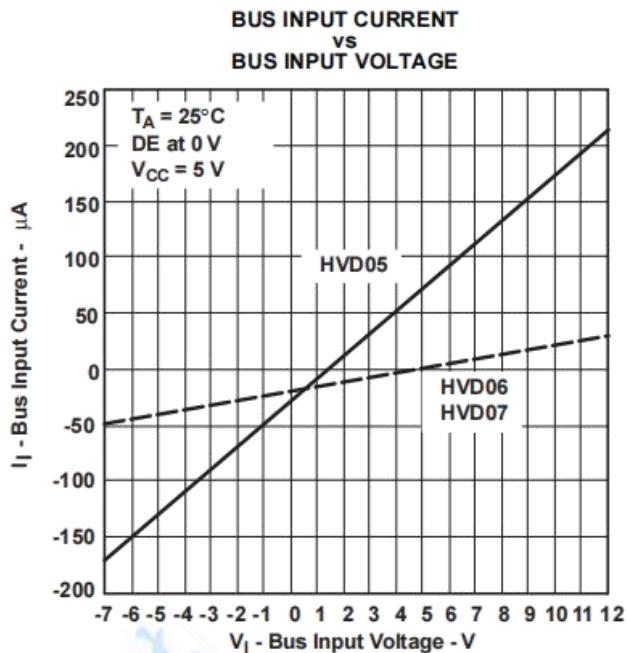


Figure 17.

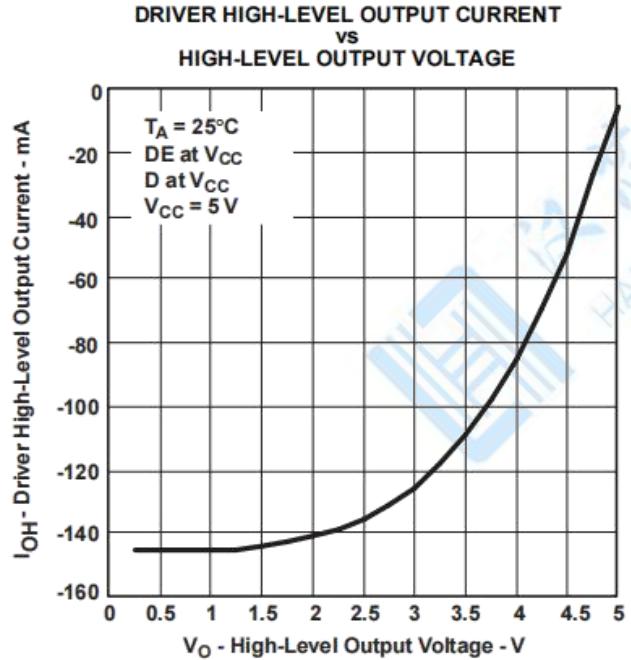


Figure 18.

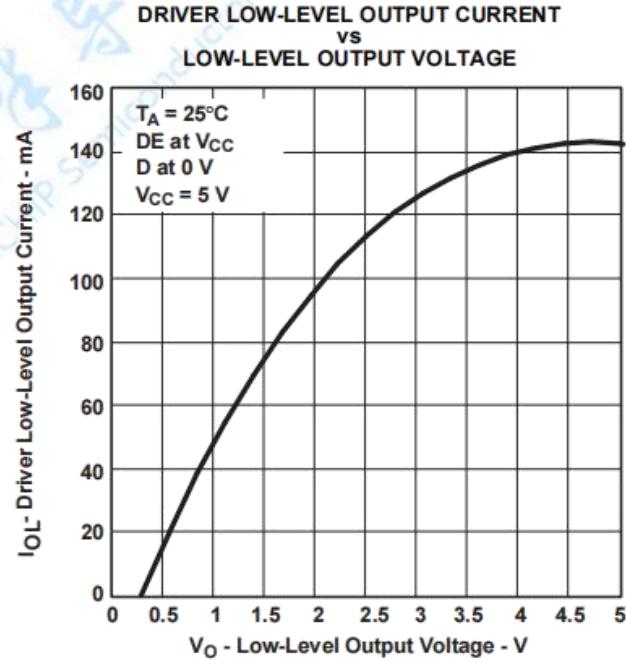


Figure 19.

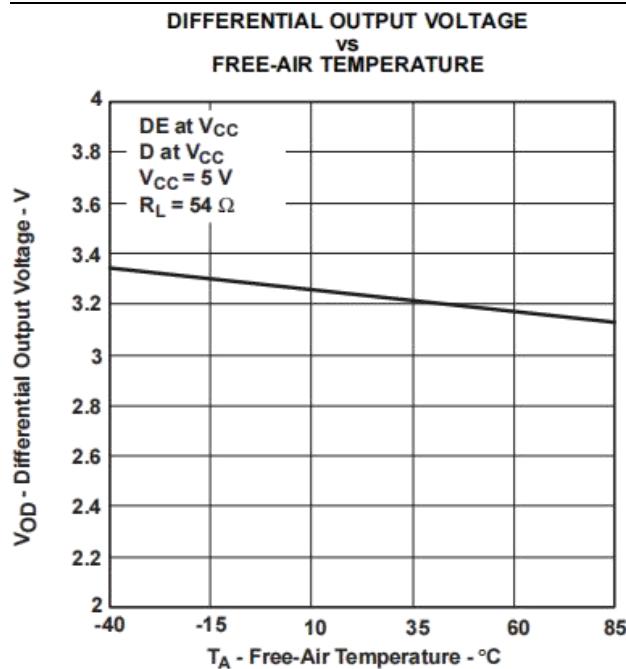


Figure 20.

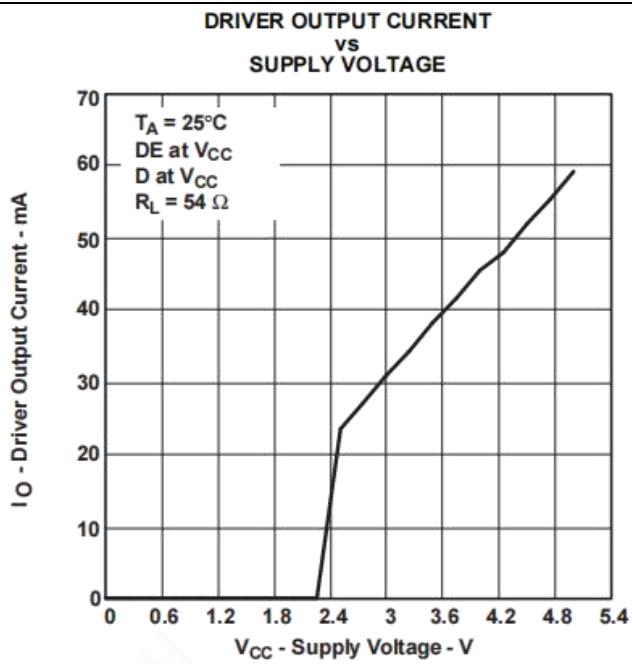


Figure 21.

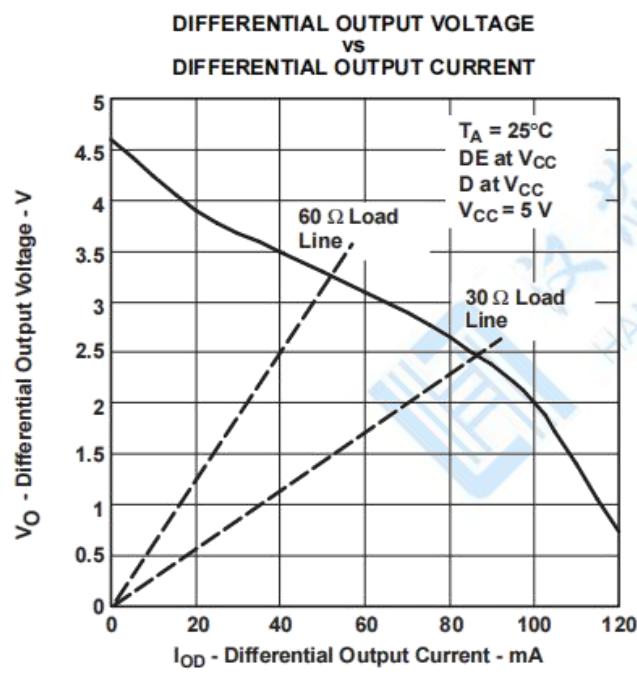


Figure 22.

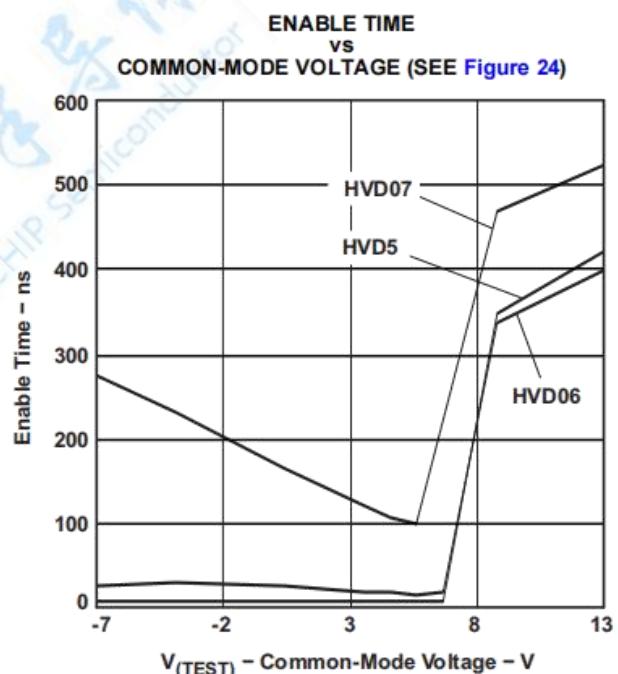


Figure 23.

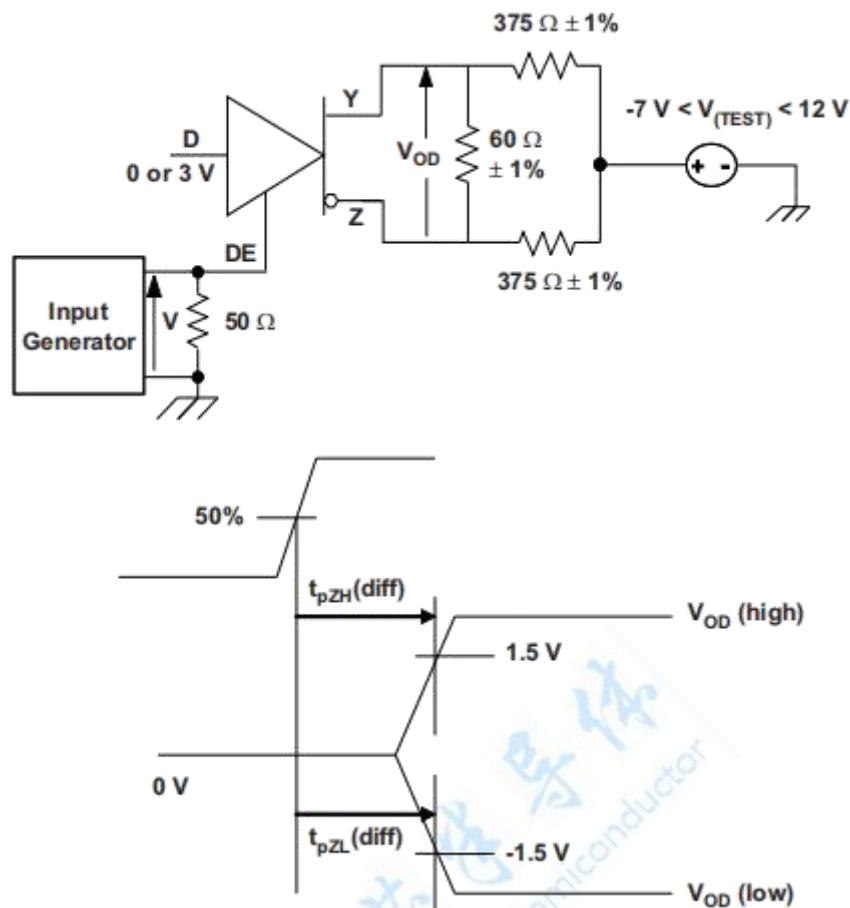
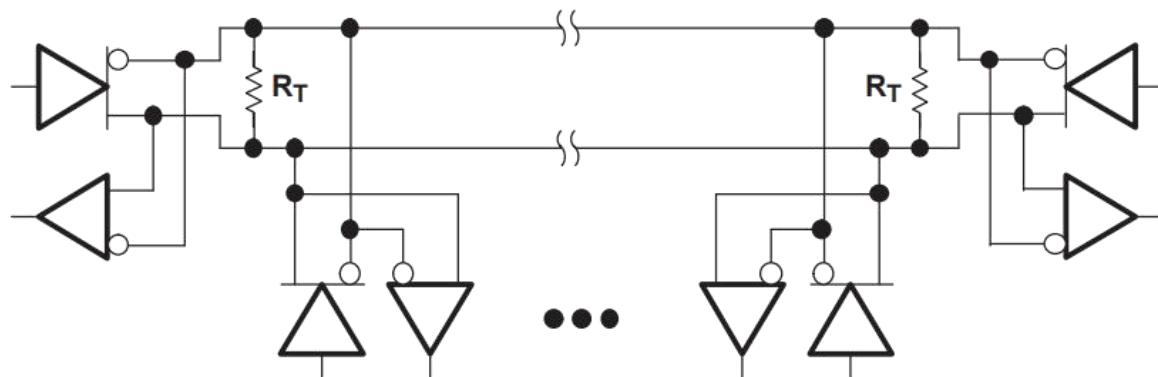


Figure 24. Driver Enable Time From DE to VOD

The time $t_{pZL}(x)$ is the measure from DE to $VOD(x)$. VOD is valid when it is greater than 1.5 V.

APPLICATION INFORMATION



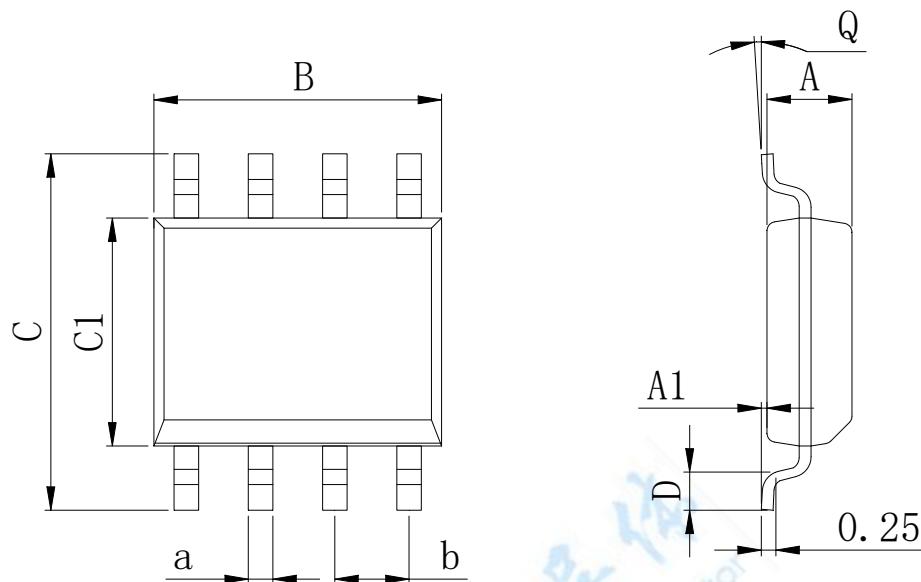
Device	Number of Devices on Bus
HVD05	64
HVD06	256
HVD07	256

NOTE: The line should be terminated at both ends with its characteristic impedance ($R_T = Z_0$).
Stub lengths off the main line should be kept as short as possible.

Figure 25. Typical Application Circuit

Physical Dimensions

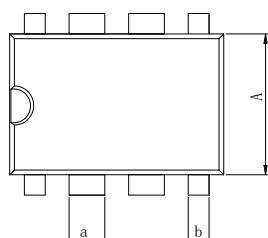
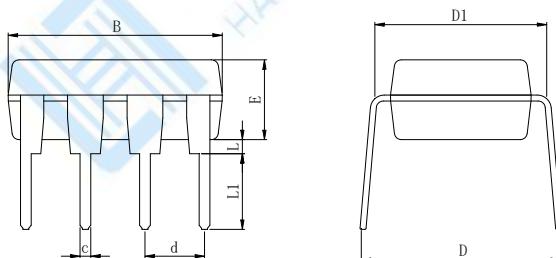
SOP8 (150mil)



Dimensions In Millimeters(SOP8)

Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	

DIP8



Dimensions In Millimeters(DIP8)

Symbol:	A	B	D	D1	E	L	L1	a	b	c	d
Min:	6.10	9.00	8.40	7.42	3.10	0.50	3.00	1.50	0.85	0.40	2.54 BSC
Max:	6.68	9.50	9.00	7.82	3.55	0.70	3.60	1.55	0.90	0.50	

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